RoHS COMPLIANT

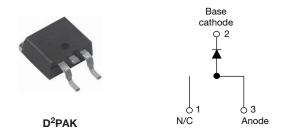
**HALOGEN** 

FREE



# Vishay Semiconductors

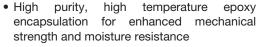
# **High Performance Schottky Rectifier, 19 A**



PRODUCT SUMMARY	PRODUCT SUMMARY					
Package	D <sup>2</sup> PAK					
I <sub>F(AV)</sub>	19 A					
$V_{R}$	15 V					
V <sub>F</sub> at I <sub>F</sub>	0.36 V					
I <sub>RM</sub> max.	522 mA at 100 °C					
T <sub>J</sub> max.	125 °C					
Diode variation	Single die					
E <sub>AS</sub>	6.75 mJ					

## **FEATURES**

- 125 °C T<sub>J</sub> operation (V<sub>R</sub> < 5 V)</li>
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

## **DESCRIPTION**

The VS-19TQ015SPbF Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	19	A				
V <sub>RRM</sub>		15	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 µs sine	700	A				
V <sub>F</sub>	19 A <sub>pk</sub> , T <sub>J</sub> = 75 °C	0.32	V				
TJ	Range	-55 to +125	°C				

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-19TQ015SPbF	UNITS
Maximum DC reverse voltage	$V_R$	15	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	15	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 80 °C,	19	А	
Maximum peak one cycle non-repetitive surge current	l=	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	700	A
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	330	A
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L = 6 mH		6.75	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximu	o in 1 µs um V <sub>A</sub> = 3 x V <sub>R</sub> typical	1.50	А

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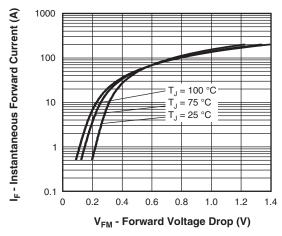
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum forward voltage drop See fig. 1		19 A	T <sub>.1</sub> = 25 °C	0.36	V
	V <sub>FM</sub> <sup>(1)</sup>	38 A	1J=25 C	0.46	
	VFM (')	19 A	T 75 00	0.32	
		38 A	- T <sub>J</sub> = 75 °C	0.43	
		T <sub>J</sub> = 100 °C, V <sub>R</sub> = 12 V	465	mA	
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	$T_J = 100  ^{\circ}\text{C},  V_R = 5  \text{V}$			285
See fig. 2		T <sub>J</sub> = 25 °C	V Dated V	10.5	IIIA
		T <sub>J</sub> = 100 °C	V <sub>R</sub> = Rated V <sub>R</sub>	522	
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	ge 100 kHz to 1 MHz), 25 °C	2000	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 r	Measured lead to lead 5 mm from package body		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

## Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction tempera	ature range	TJ		-55 to +125	°C
Maximum storage tempera	ture range	T <sub>Stg</sub>		-55 to +150	C
Maximum thermal resistance junction to case	ce,	R <sub>thJC</sub>	DC operation See fig. 4	1.50	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	C/VV
Annewingsto weight				2	g
Approximate weight				0.07	OZ.
minimum				6 (5)	kgf · cm
Mounting torque maximum				12 (10)	(lbf · in)
Marking device			Case style D <sup>2</sup> PAK	19TQ	015S





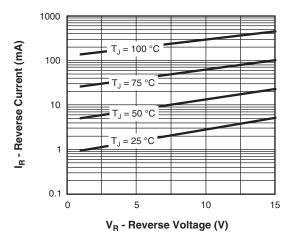


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



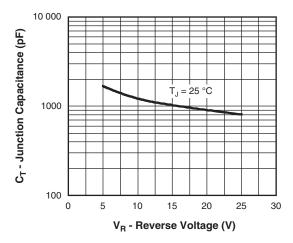


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

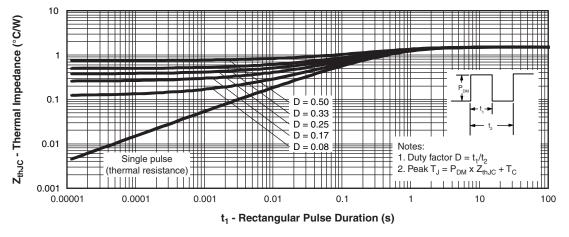


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

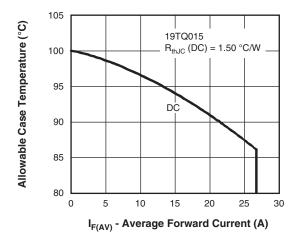


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

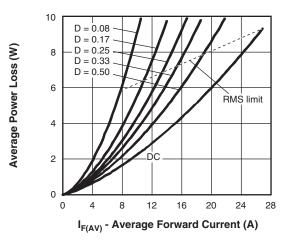
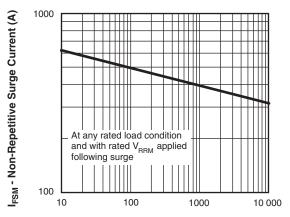


Fig. 6 - Forward Power Loss Characteristics

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t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

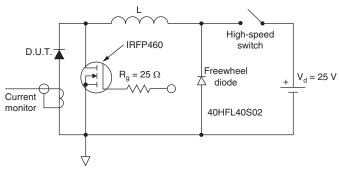


Fig. 8 - Unclamped Inductive Test Circuit

# **ORDERING INFORMATION TABLE**

Device code	VS-	19	Т	Q	015	S	TRL	PbF
	1	2	3	4	5	6	7	8
	1 .	Visl	nay Sem	niconduc	ctors pro	oduct		
	2	Cur	rent rati	ng (19 A	A)			
	3 -	Circ	cuit conf	iguratior	n: T = T	O-220		
	4	Sch	ottky "Q	" series				
	5 -	· Volt	tage rati	ng (015	= 15 V)	)		
	6	S =	$D^2PAK$					
	7	• N	one = tu	ibe (50 p	oieces)			
		• TI	RL = tap	e and re	eel (left	oriente	d)	
		• TI	RR = tap	oe and r	eel (righ	nt orient	ed)	
	8 -	PbF	= lead	(Pb)-fre	e			

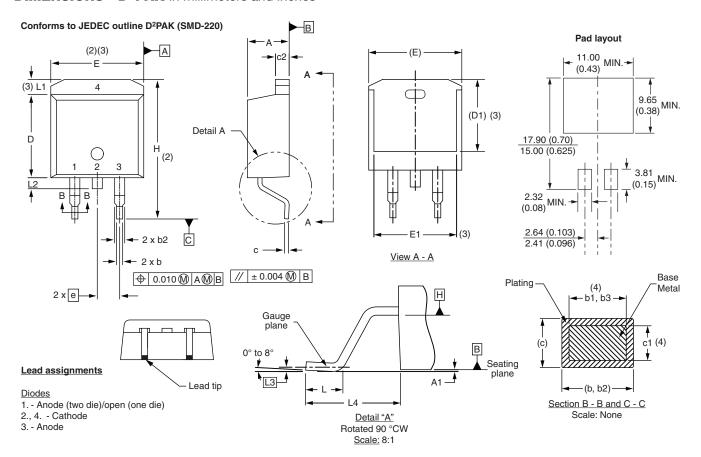
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?96005			

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# Vishay Semiconductors

# **D**<sup>2</sup>**PAK**, **TO**-262

# **DIMENSIONS - D<sup>2</sup>PAK** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		e 2.54 BSC 0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	·
L4	4.78	5.28	0.188	0.208	

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

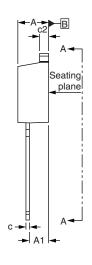
(7) Outline conforms to JEDEC outline TO-263AB

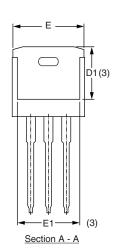
Document Number: 95014 Revision: 31-Mar-09



# **DIMENSIONS - TO-262** in millimeters and inches

# Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) A (3) A (4) C (C) C (Datum A) (2) (3) (3) A (4) A (5) C (6) C (7) C (7) C (8) A (9) A (10) A (10)





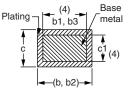
**♦**0.010**⋒**A**⋒**B

### Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIN	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

# Notes

- $^{(1)}$  Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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